



Appendix B. HAC Measurement Plots

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HAC Measurement Plots of GSM850
HAC Measurement Plots of GSM1900

Test Laboratory: HUAWEI SAR/HAC Lab

HAC_ER3DV6_Y536A1-GSM850-251CH

DUT: Y536A1; Type: Smart Phone; Serial: SAR1

Communication System: UID 10021 - DAA, GSM-FDD (TDMA, GMSK); Frequency: 848.8 MHz;Duty Cycle: 1:8.6896

Medium parameters used: $\sigma = 0 \text{ S/m}$, $\epsilon_r = 1$; $\rho = 0 \text{ kg/m}^3$

Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2441; ConvF(1, 1, 1); Calibrated: 2013-11-29;
- Sensor-Surface: (Fix Surface), $z = 8.7$
- Electronics: DAE4 Sn1236; Calibrated: 2013-11-25
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: $dx=0.5000 \text{ mm}$, $dy=0.5000 \text{ mm}$

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 76.15 V/m; Power Drift = 0.02 dB

Applied MIF = 3.63 dB

RF audio interference level = 39.03 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 38.58 dBV/m	Grid 2 M4 38.98 dBV/m	Grid 3 M4 38.75 dBV/m
Grid 4 M4 38.29 dBV/m	Grid 5 M4 39.03 dBV/m	Grid 6 M4 38.8 dBV/m
Grid 7 M4 37.78 dBV/m	Grid 8 M4 38.54 dBV/m	Grid 9 M4 38.31 dBV/m

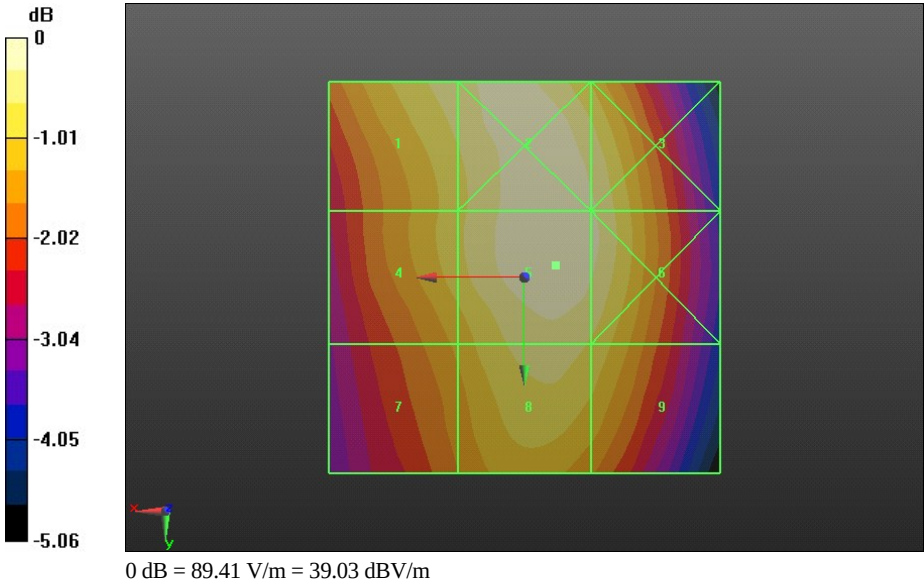
Category	Limits for E-Field Emissions < 960MHz	Limits for E-Field Emissions > 960MHz
M1	50 dBV/m - 55 dB V/m	40 dBV/m - 45 dB V/m
M2	45 dBV/m - 50 dB V/m	35 dBV/m - 40 dB V/m
M3	40 dBV/m - 45 dB V/m	30 dBV/m - 35 dB V/m
M4	<40 dBV/m	<30 dBV/m

Cursor:

Total = 39.03 dBV/m

E Category: M4

Location: -4, -1.5, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

HAC_ER3DV6_Y536A1-GSM850-190CH

DUT: Y536A1; Type: Smart Phone; Serial: SAR1

Communication System: UID 10021 - DAA, GSM-FDD (TDMA, GMSK); Frequency: 836.6 MHz;Duty Cycle: 1:8.6896

Medium parameters used: $\sigma = 0 \text{ S/m}$, $\epsilon_r = 1$; $\rho = 0 \text{ kg/m}^3$

Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2441; ConvF(1, 1, 1); Calibrated: 2013-11-29;
- Sensor-Surface: (Fix Surface), $z = 8.7$
- Electronics: DAE4 Sn1236; Calibrated: 2013-11-25
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: $dx=0.5000 \text{ mm}$, $dy=0.5000 \text{ mm}$

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 81.71 V/m; Power Drift = 0.01 dB

Applied MIF = 3.63 dB

RF audio interference level = 39.57 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 39.14 dBV/m	Grid 2 M4 39.53 dBV/m	Grid 3 M4 39.28 dBV/m
Grid 4 M4 38.85 dBV/m	Grid 5 M4 39.57 dBV/m	Grid 6 M4 39.31 dBV/m
Grid 7 M4 38.43 dBV/m	Grid 8 M4 39.12 dBV/m	Grid 9 M4 38.87 dBV/m

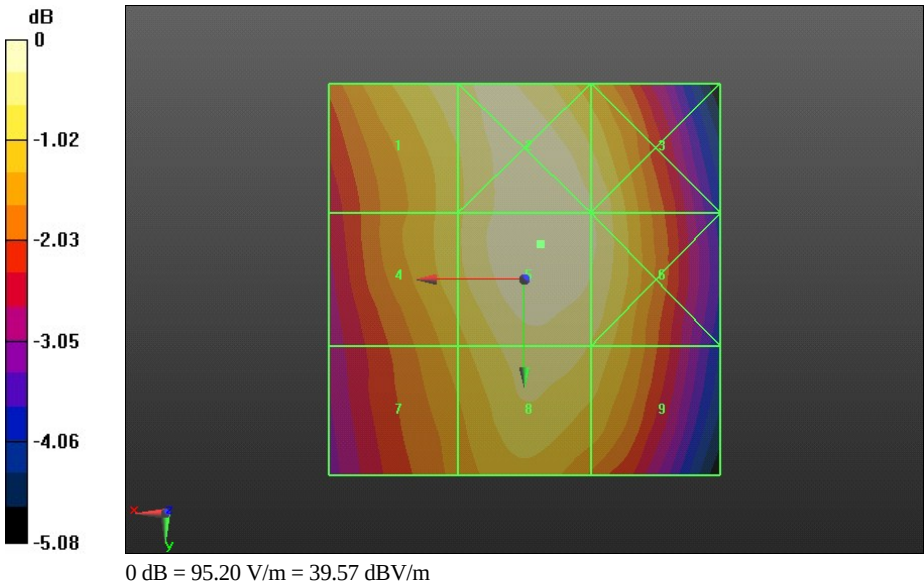
Category	Limits for E-Field Emissions < 960MHz	Limits for E-Field Emissions > 960MHz
M1	50 dBV/m - 55 dB V/m	40 dBV/m - 45 dB V/m
M2	45 dBV/m - 50 dB V/m	35 dBV/m - 40 dB V/m
M3	40 dBV/m - 45 dB V/m	30 dBV/m - 35 dB V/m
M4	<40 dBV/m	<30 dBV/m

Cursor:

Total = 39.57 dBV/m

E Category: M4

Location: -2, -4.5, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

HAC_ER3DV6_Y536A1-GSM850-128CH

DUT: Y536A1; Type: Smart Phone; Serial: SAR1

Communication System: UID 10021 - DAA, GSM-FDD (TDMA, GMSK); Frequency: 824.2 MHz;Duty Cycle: 1:8.6896

Medium parameters used: $\sigma = 0 \text{ S/m}$, $\epsilon_r = 1$; $\rho = 0 \text{ kg/m}^3$

Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2441; ConvF(1, 1, 1); Calibrated: 2013-11-29;
- Sensor-Surface: (Fix Surface), $z = 8.7$
- Electronics: DAE4 Sn1236; Calibrated: 2013-11-25
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: $dx=0.5000 \text{ mm}$, $dy=0.5000 \text{ mm}$

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 85.56 V/m; Power Drift = -0.07 dB

Applied MIF = 3.63 dB

RF audio interference level = 39.91 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4 39.47 dBV/m	Grid 2 M4 39.85 dBV/m	Grid 3 M4 39.55 dBV/m
Grid 4 M4 39.27 dBV/m	Grid 5 M4 39.91 dBV/m	Grid 6 M4 39.59 dBV/m
Grid 7 M4 38.78 dBV/m	Grid 8 M4 39.4 dBV/m	Grid 9 M4 39.17 dBV/m

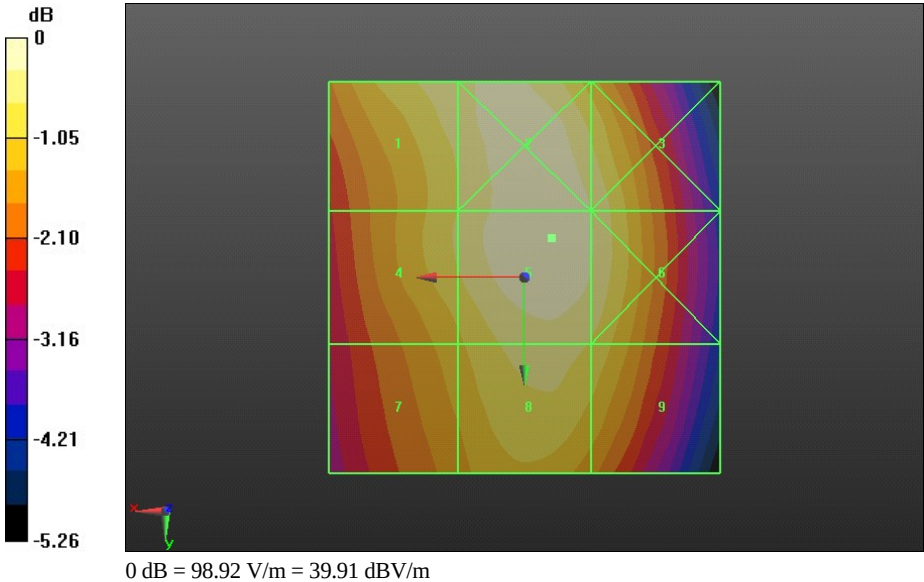
Category	Limits for E-Field Emissions < 960MHz	Limits for E-Field Emissions > 960MHz
M1	50 dBV/m - 55 dB V/m	40 dBV/m - 45 dB V/m
M2	45 dBV/m - 50 dB V/m	35 dBV/m - 40 dB V/m
M3	40 dBV/m - 45 dB V/m	30 dBV/m - 35 dB V/m
M4	<40 dBV/m	<30 dBV/m

Cursor:

Total = 39.91 dBV/m

E Category: M4

Location: -3.5, -5, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

HAC_ER3DV6_Y536A1-GSM1900-810CH

DUT: Y536A1; Type: Smart Phone; Serial: SAR1

Communication System: UID 10021 - DAA, GSM-FDD (TDMA, GMSK); Frequency: 1909.8 MHz;Duty Cycle: 1:8.6896
Medium parameters used: $\sigma = 0 \text{ S/m}$, $\epsilon_r = 1$; $\rho = 0 \text{ kg/m}^3$
Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2441; ConvF(1, 1, 1); Calibrated: 2013-11-29;
- Sensor-Surface: (Fix Surface), $z = 8.7$
- Electronics: DAE4 Sn1236; Calibrated: 2013-11-25
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: $dx=0.5000 \text{ mm}$, $dy=0.5000 \text{ mm}$

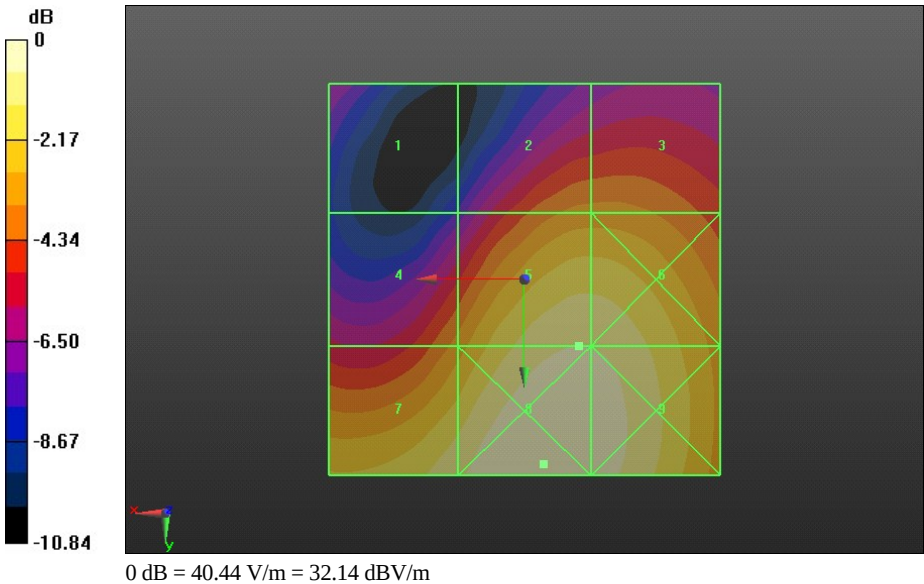
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 26.08 V/m; Power Drift = -0.00 dB
Applied MIF = 3.63 dB
RF audio interference level = 31.42 dBV/m
Emission category: M3

MIF scaled E-field

Grid 1 M4 25.87 dBV/m	Grid 2 M4 28.82 dBV/m	Grid 3 M4 28.85 dBV/m
Grid 4 M4 28.88 dBV/m	Grid 5 M3 31.42 dBV/m	Grid 6 M3 31.4 dBV/m
Grid 7 M3 31.26 dBV/m	Grid 8 M3 32.14 dBV/m	Grid 9 M3 31.92 dBV/m

Category	Limits for E-Field Emissions < 960MHz	Limits for E-Field Emissions > 960MHz
M1	50 dBV/m - 55 dB V/m	40 dBV/m - 45 dB V/m
M2	45 dBV/m - 50 dB V/m	35 dBV/m - 40 dB V/m
M3	40 dBV/m - 45 dB V/m	30 dBV/m - 35 dB V/m
M4	<40 dBV/m	<30 dBV/m

Cursor:
Total = 32.14 dBV/m
E Category: M3
Location: -2.5, 23.5, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

HAC_ER3DV6_Y536A1-GSM1900-661CH

DUT: Y536A1; Type: Smart Phone; Serial: SAR1

Communication System: UID 10021 - DAA, GSM-FDD (TDMA, GMSK); Frequency: 1880 MHz;Duty Cycle: 1:8.6896

Medium parameters used: $\sigma = 0 \text{ S/m}$, $\epsilon_r = 1$; $\rho = 0 \text{ kg/m}^3$

Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2441; ConvF(1, 1, 1); Calibrated: 2013-11-29;
- Sensor-Surface: (Fix Surface), $z = 8.7$
- Electronics: DAE4 Sn1236; Calibrated: 2013-11-25
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: $dx=0.5000 \text{ mm}$, $dy=0.5000 \text{ mm}$

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 28.71 V/m; Power Drift = 0.02 dB

Applied MIF = 3.63 dB

RF audio interference level = 31.96 dBV/m

Emission category: M3

MIF scaled E-field

Grid 1 M4 25.36 dBV/m	Grid 2 M3 30.07 dBV/m	Grid 3 M3 30.09 dBV/m
Grid 4 M4 28.77 dBV/m	Grid 5 M3 31.96 dBV/m	Grid 6 M3 31.95 dBV/m
Grid 7 M3 30.95 dBV/m	Grid 8 M3 32.24 dBV/m	Grid 9 M3 32.18 dBV/m

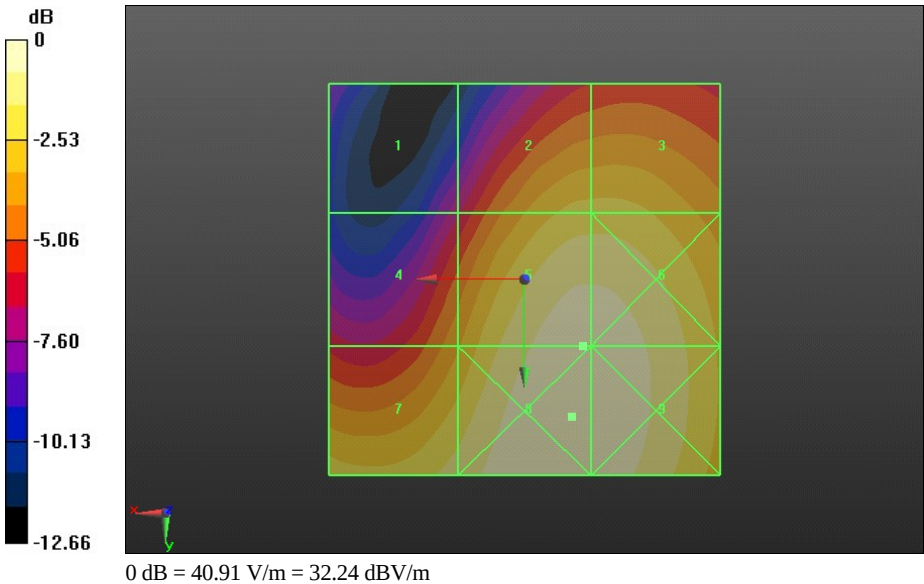
Category	Limits for E-Field Emissions < 960MHz	Limits for E-Field Emissions > 960MHz
M1	50 dBV/m - 55 dB V/m	40 dBV/m - 45 dB V/m
M2	45 dBV/m - 50 dB V/m	35 dBV/m - 40 dB V/m
M3	40 dBV/m - 45 dB V/m	30 dBV/m - 35 dB V/m
M4	<40 dBV/m	<30 dBV/m

Cursor:

Total = 32.24 dBV/m

E Category: M3

Location: -6, 17.5, 8.7 mm



Test Laboratory: HUAWEI SAR/HAC Lab

HAC_ER3DV6_Y536A1-GSM1900-512CH

DUT: Y536A1; Type: Smart Phone; Serial: SAR1

Communication System: UID 10021 - DAA, GSM-FDD (TDMA, GMSK); Frequency: 1850.2 MHz;Duty Cycle: 1:8.6896

Medium parameters used: $\sigma = 0 \text{ S/m}$, $\epsilon_r = 1$; $\rho = 0 \text{ kg/m}^3$

Phantom section: RF Section

DASY Configuration:

- Probe: ER3DV6 - SN2441; ConvF(1, 1, 1); Calibrated: 2013-11-29;
- Sensor-Surface: (Fix Surface), z = 8.7
- Electronics: DAE4 Sn1236; Calibrated: 2013-11-25
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1053
- DASY52 52.8.7(1137); SEMCAD X 14.6.10(7164)

Device E-Field measurement (E-field scan for ANSI C63.19-2011 compliance)/E Scan - ER3D: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 30.97 V/m; Power Drift = -0.02 dB

Applied MIF = 3.63 dB

RF audio interference level = 32.45 dBV/m

Emission category: M3

MIF scaled E-field

Grid 1 M4 26.29 dBV/m	Grid 2 M3 30.59 dBV/m	Grid 3 M3 30.6 dBV/m
Grid 4 M4 29.34 dBV/m	Grid 5 M3 32.45 dBV/m	Grid 6 M3 32.43 dBV/m
Grid 7 M3 30.84 dBV/m	Grid 8 M3 32.6 dBV/m	Grid 9 M3 32.57 dBV/m

Category	Limits for E-Field Emissions < 960MHz	Limits for E-Field Emissions > 960MHz
M1	50 dBV/m - 55 dB V/m	40 dBV/m - 45 dB V/m
M2	45 dBV/m - 50 dB V/m	35 dBV/m - 40 dB V/m
M3	40 dBV/m - 45 dB V/m	30 dBV/m - 35 dB V/m
M4	<40 dBV/m	<30 dBV/m

Cursor:

Total = 32.60 dBV/m

E Category: M3

Location: -6.5, 15.5, 8.7 mm

